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Surface Mount Glass Passivated Junction Rectifiers Reverse Voltage 50V to 1000V Forward Current 3A



Features

- For surface mounted applications
- Glass passivated junction chip
- Low profile package
- Built-in stain relief, ideal for automatic placement
- \bullet High temperature soldering guaranteed : 260 $^{\circ}\text{C}/10$ seconds at terminals
- Plastic material used carries UL flammability classification 94V-0

Mechanical Data

- Case: JEDEC DO-214AC(SMA) molded plastic
- Terminals: Pure tin plated, solderable per MIL-STD-750 method 2026
- Polarity: Color band denotes cathode end
- Mounting position : Any
- Weight: 0.064 gram, 0.002 ounce

Ordering Information

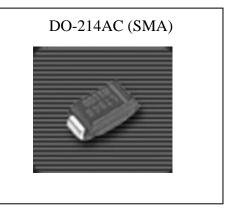
Device	Package Shipping			
S3A-0-T4-G			S3A	
S3B-0-T4-G			S3B	
S3D-0-T4-G	SMA		S3D	
S3G-0-T4-G	(Pb-free lead plating and halogen-free	7500 pcs / Tape & Reel	S3G	
S3J-0-T4-G	package)		S3J	
S3K-0-T4-G			S3K	
S3M-0-T4-G			S3M	
	Environment friendly grade : S for RoHS con green compound products	npliant products, G for RoHS co	mpliant and	

Packing spec, T4 : 7500 pcs / tape & reel, 13" reel

Product rank, zero for no rank products

- Product name

Outline





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Maximum Ratings and Electrical Characteristics

(Rating at 25°C ambient temperature unless otherwise specified. Single phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.)

Parameter		Symbol	Туре						Units	
r arameter	Symbol	S3A	S3B	S3D	S3G	S3J	S3K	S3M	Units	
Maximum repetitive peak reverse	VRRM	50	100	200	400	600	800	1000	V	
Maximum RMS voltage				70	140	280	420	560	700	V
Maximum DC blocking voltage		VR	50	100	200	400	600	800	1000	V
Maximum instantaneous forward v	voltage, IF=1A	VF	1.2							V
Maximum average forward rectified current, see Fig. 1		IF(AV)	3							А
Peak forward surge current @8.3ms single half sine wave superimposed on rated load (JEDEC method) TL=90°C		Ifsm	100						А	
Maximum DC reverse current at Rated DC blocking voltage	$T_{A}=25^{\circ}C$ $T_{A}=125^{\circ}C$	IR	10 250					μA		
Typical reverse recovery time (Note	trr	2.5						μs		
Typical junction capacitance @ f=1MHz and applied 4V reverse voltage		CJ	55						pF	
Typical thermal resistance (Note 2)		$R_{\theta JA}$	50						°C/W	
· · · · · · · · · · · · · · · · · · ·	$R_{\theta JL}$	90								
Operating junction and Storage ten	Tj;Tstg	-55 ~ +150							°C	

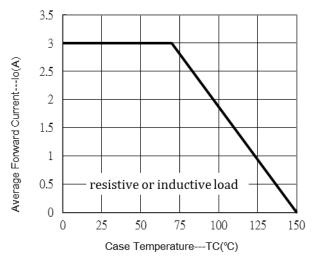
Note: 1.Reverse recovery test conditions : IF=0.5A, IR=1A, IRR=0.25A

2. Thermal resistance from junction to ambient and from junction to lead mounted on PCB with 0.2"x0.2"(5mmx5mm) copper pad areas.



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Ratings and Characteristic Curves





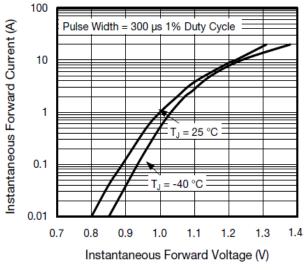


Fig. 3 - Typical Instantaneous Forward Characteristics

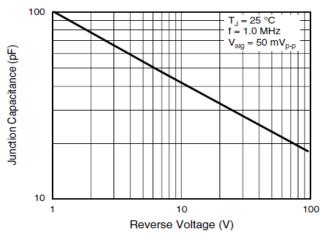


Fig. 5 - Typical Junction Capacitance

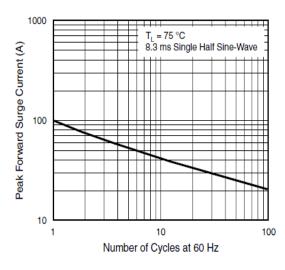


Fig. 2 - Maximum Non-Repetitive Peak Forward Surge Current

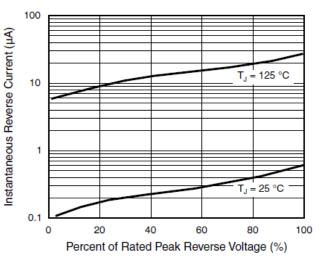


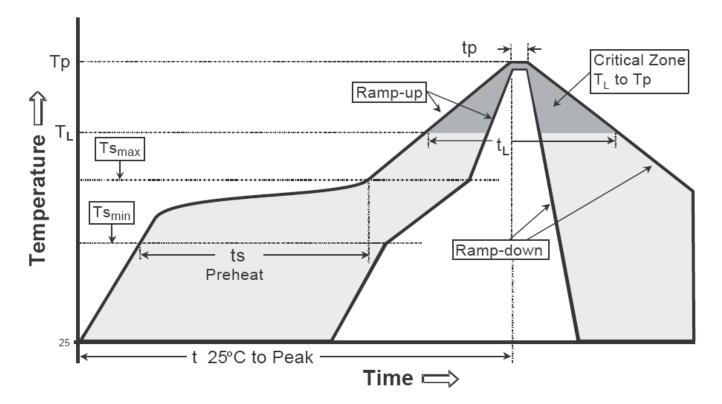
Fig. 4 - Typical Reverse Characteristics



Recommended wave soldering condition

Product	Peak Temperature	Soldering Time		
Pb-free devices	260 +0/-5 °C	5 +1/-1 seconds		

Recommended temperature profile for IR reflow



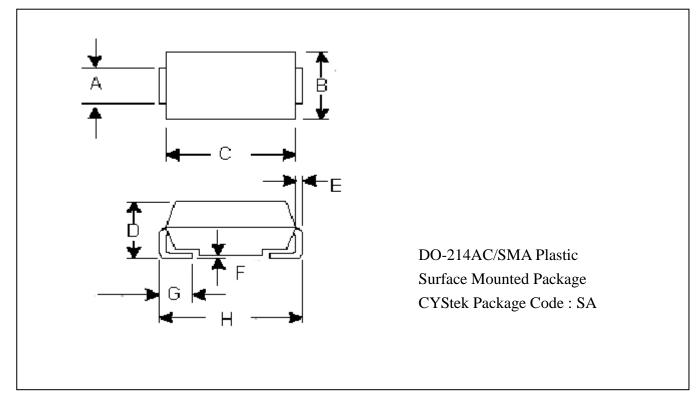
Profile feature	Sn-Pb eutectic Assembly	Pb-free Assembly		
Average ramp-up rate (Tsmax to Tp)	3°C/second max.	3°C/second max.		
Preheat				
-Temperature Min(Ts min)	100°C	150°C		
-Temperature Max(Ts max)	150°C	200°C		
–Time(ts min to ts max)	60-120 seconds	60-180 seconds		
Time maintained above:				
–Temperature (TL)	183°C	217°C		
– Time (t∟)	60-150 seconds	60-150 seconds		
Peak Temperature(T _P)	240 +0/-5 °C	260 +0/-5 °C		
Time within 5°C of actual peak temperature(tp)	10-30 seconds	20-40 seconds		
Ramp down rate	6°C/second max.	6°C/second max.		
Time 25 °C to peak temperature	6 minutes max.	8 minutes max.		

Note : All temperatures refer to topside of the package, measured on the package body surface.



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DO-214AC/SMA Dimension



DIM	Inches		Millimeters		DIM	Inches		Millimeters	
DIIVI	Min.	Max.	Min.	Max.	DIIVI	Min.	Max.	Min.	Max.
А	0.049	0.065	1.25	1.65	E	0.006	0.012	0.15	0.31
В	0.100	0.110	2.54	2.79	F	0.004	0.008	0.10	0.20
С	0.157	0.177	3.99	4.50	G	0.030	0.060	0.76	1.50
D	0.078	0.090	1.98	2.29	Н	0.194	0.208	4.91	5.28

Notes : 1.Controlling dimension : millimeters.

2.Maximum lead thickness includes lead finish thickness, and minimum lead thickness is the minimum thickness of base material. 3.If there is any question with packing specification or packing method, please contact your local CYStek sales office.

Material :

• Lead : Pure tin plated.

• Mold Compound : Epoxy resin family, flammability solid burning class:UL94V-0.

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